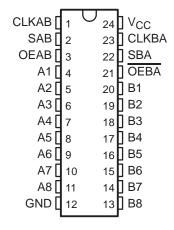
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- State-of-the-Art *EPIC-IIB™* BiCMOS Design **Significantly Reduces Power Dissipation**
- **ESD Protection Exceeds 2000 V Per** MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 500 mA Per **JESD 17**
- Typical V_{OLP} (Output Ground Bounce) < 1 V at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$
- High-Drive Outputs (-32-mA IOH, 64-mA IOI)
- **Multiplexed Real-Time and Stored Data**
- **Inverting Data Paths**
- **Package Options Include Plastic** Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Chip Carriers (FK), and Plastic (NT) and Ceramic (JT) DIPs

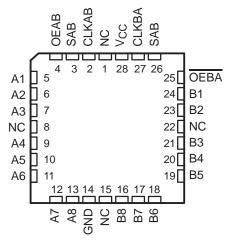
description

These devices consist of bus-transceiver circuits. D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the data bus or from the internal storage registers. Output-enable (OEAB and OEBA) inputs are provided to control the transceiver functions. The select-control (SAB and SBA) inputs are provided to select whether real-time or stored data is transferred. A low input level selects real-time data, and a high input level selects stored data. Figure 1 illustrates the four fundamental bus-management functions that performed with the 'ABT651 devices.

SN54ABT651 . . . JT PACKAGE SN74ABT651...DB, DW, NT, OR PW PACKAGE (TOP VIEW)



SN54ABT651 ... FK PACKAGE (TOP VIEW)



NC - No internal connection

Data on the A or B bus, or both, can be stored in the internal D flip-flops by low-to-high transitions at the appropriate clock (CLKAB or CLKBA) inputs, regardless of the select- or enable-control pins. When SAB and SBA are in the real-time transfer mode, it also is possible to store data without using the internal D-type flip-flops by simultaneously enabling OEAB and OEBA. In this configuration, each output reinforces its input. When all the other data sources to the two sets of bus lines are at high impedance, each set remains at its last state.

To ensure the high-impedance state during power up or power down, OEBA should be tied to VCC through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver (B to A). OEAB should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver (A to B).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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description (continued)

The SN54ABT651 is characterized for operation over the full military temperature range of -55° C to 125° C. The SN74ABT651 is characterized for operation from -40° C to 85° C.

FUNCTION TABLE

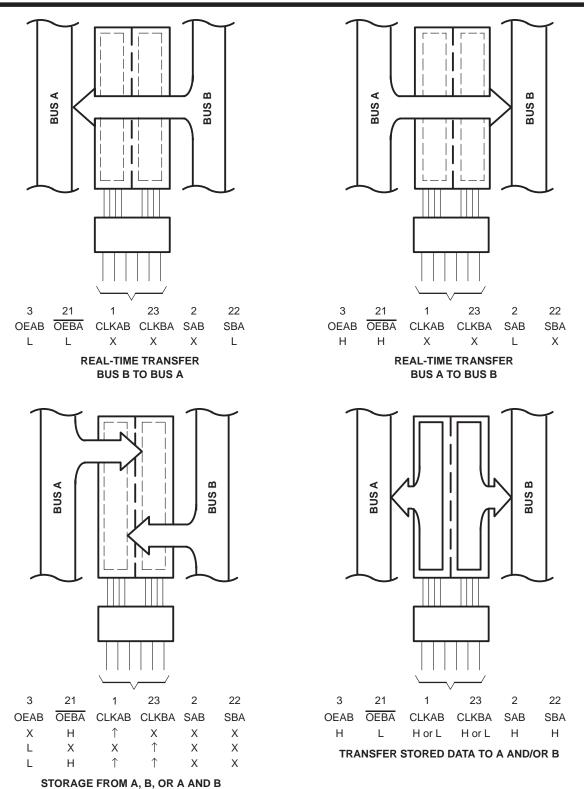
		INPU ⁻	rs			DAT	A I/O	OPERATION OR FUNCTION
OEAB	OEBA	CLKAB	CLKBA	SAB	SBA	A1-A8	B1-B8	OPERATION OR FUNCTION
L	Н	H or L	H or L	Х	Х	Input	Input	Isolation
L	Н	1	1	X	X	Input	Input	Store A and B data
Х	Н	1	H or L	Х	Х	Input	Unspecified [†]	Store A, hold B
Н	Н	\uparrow	1	X‡	X	Input	Output	Store A in both registers
L	Х	H or L	1	Х	Х	Unspecified [†]	Input	Hold A, store B
L	L	1	1	Χ	X‡	Output	Input	Store B in both registers
L	L	Х	Χ	Х	L	Output	Input	Real-time B data to A bus
L	L	Χ	H or L	X	Н	Output	Input	Stored \overline{B} data to A bus
Н	Н	Χ	Χ	L	Х	Input	Output	Real-time A data to B bus
Н	Н	H or L	Χ	Н	X	Input	Output	Stored \overline{A} data to B bus
Н	L	H or L	H or L	Н	Н	Output	Output	Stored A data to B bus and stored B data to A bus

[†] The data output functions may be enabled or disabled by a variety of level combinations at OEAB or OEBA. Data input functions are always enabled; i.e., data at the bus terminals is stored on every low-to-high transition of the clock inputs.



[‡] When select control is low, clocks can occur simultaneously if allowances are made for propagation delays from A to B (B to A) plus setup and hold times. When select control is high, clocks must be staggered to load both registers.

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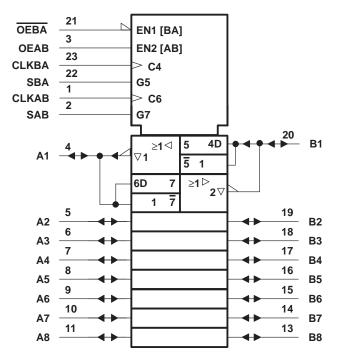
Pin numbers are for the DB, DW, JT, NT, and PW packages.

Figure 1. Bus-Management Functions



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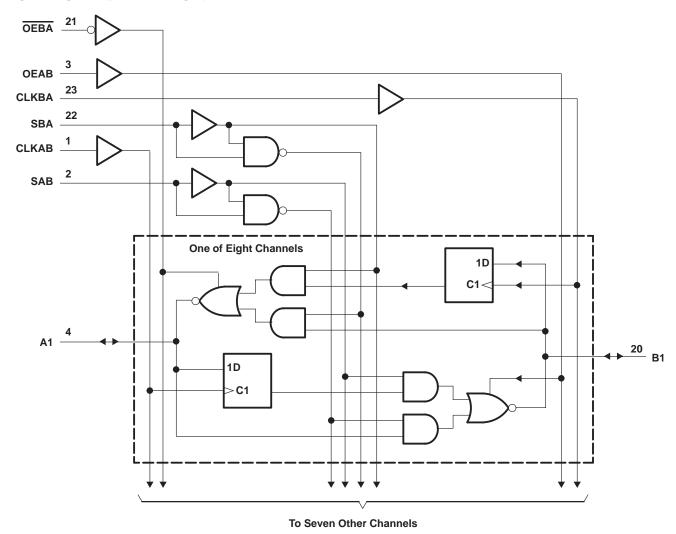
logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the DB, DW, JT, NT, and PW packages.



logic diagram (positive logic)



Pin numbers shown are for the DB, DW, JT, NT, and PW packages.

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}		0.5 V to 7 V
Input voltage range, V _I (except I/O ports) (see N		
Voltage range applied to any output in the high	or power-off state, VO	
Current into any output in the low state, IO: SN	54ABT651	96 mA
SN ⁻	74ABT651	128 mA
Input clamp current, I _{IK} (V _I < 0)		–18 mA
Output clamp current, I _{OK} (V _O < 0)		–50 mA
Package thermal impedance, θ_{JA} (see Note 2):	DB package	104°C/W
***	DW package	81°C/W
	NT package	67°C/W
	PW package	120°C/W
Storage temperature range, T _{stg}		–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

recommended operating conditions (see Note 3)

		SN54A	BT651	SN74A	BT651	UNIT
		MIN	MAX	MIN	MAX	UNIT
Vcc	Supply voltage	4.5	5.5	4.5	5.5	V
VIH	High-level input voltage	2	EN	2		V
VIL	Low-level input voltage		0.8		0.8	V
٧ı	Input voltage	0 <	Vcc	0	VCC	V
IOH	High-level output current	(ر)	-24		-32	mA
lOL	Low-level output current	$g_{Q_{\ell}}$	48		64	mA
Δt/Δν	Input transition rise or fall rate) V	5		5	ns/V
TA	Operating free-air temperature	– 55	125	-40	85	°C

NOTE 3: All unused pins (control or I/O) of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

^{2.} The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CON	T _A = 25°C			SN54ABT651		SN74ABT651		UNIT		
PARAMETER	TEST CON	ADITIONS	MIN	TYP†	MAX	MIN	MAX	MIN	MAX	UNII	
VIK	V _{CC} = 4.5 V,	I _I = -18 mA			-1.2		-1.2		-1.2	V	
	$V_{CC} = 4.5 \text{ V},$	$I_{OH} = -3 \text{ mA}$	2.5			2.5		2.5			
Va	$V_{CC} = 5 V$,	$I_{OH} = -3 \text{ mA}$	3			3		3		V	
VOH	V _{CC} = 4.5 V	$I_{OH} = -24 \text{ mA}$	2			2				v	
	VCC = 4.5 V	$I_{OH} = -32 \text{ mA}$	2*					2			
VOL	V _{CC} = 4.5 V	I _{OL} = 48 mA			0.55		0.55			V	
VOL	VCC = 4.5 V	$I_{OL} = 64 \text{ mA}$			0.55*				0.55	V	
V _{hys}				100			4			mV	
Control inputs	V _{CC} = 5.5 V,	V _I = V _{CC} or GND			±1		<u></u> ±1		±1	μΑ	
A or B ports	VCC = 3.5 V,	1 = 100 01 014D			±100		±100		±100	μι	
lozh [‡]	$V_{CC} = 5.5 \text{ V},$	$V_0 = 2.7 \text{ V}$			50		50		50	μΑ	
l _{OZL} ‡	$V_{CC} = 5.5 \text{ V},$	V _O = 0.5 V			-50	S	-50		-50	μΑ	
l _{off}	$V_{CC} = 0$,	V_I or $V_O \le 4.5 \text{ V}$			±100	0			±100	μΑ	
ICEX	V _{CC} = 5.5 V, V _O = 5.5 V	Outputs high			50	40	50		50	μА	
IO§	V _{CC} = 5.5 V,	$V_0 = 2.5 \text{ V}$	-50	-100	-180	-50	-180	-50	-180	mA	
	V _{CC} = 5.5 V,	Outputs high			250		250		250	μΑ	
Icc	$I_{O} = 0$,	Outputs low			30		30		30	mA	
	$V_I = V_{CC}$ or GND	Outputs disabled			250		250		250	μΑ	
ΔICC¶	V _{CC} = 5.5 V, One input at 3.4 V, Other inputs at V _{CC} or GND				1.5		1.5		1.5	mA	
C _i Control inputs	V _I = 2.5 V or 0.5 V			6						pF	
C _{io} A or B ports	V _O = 2.5 V or 0.5 V			7.5						pF	

^{*} On products compliant to MIL-PRF-38535, this parameter does not apply.

timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 2)

		V _{CC} :	$V_{CC} = 5 V$, $T_A = 25^{\circ}C$		SN54ABT651		SN74ABT651	
		MIN	MAX	MIN	MAX	MIN	MAX	
fclock	Clock frequency		125		125		125	MHz
t _W	Pulse duration, CLK high or low	4		4	10,71	4		ns
t _{su}	Setup time, A or B before CLKAB↑ or CLKBA↑	3		3	71.	3		ns
t _h	Hold time, A or B after CLKAB↑ or CLKBA↑	0		0		0		ns

[†] All typical values are at $V_{CC} = 5 \text{ V}$.

[‡] The parameters I_{OZH} and I_{OZL} include the input leakage current.

[§] Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

 $[\]P$ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

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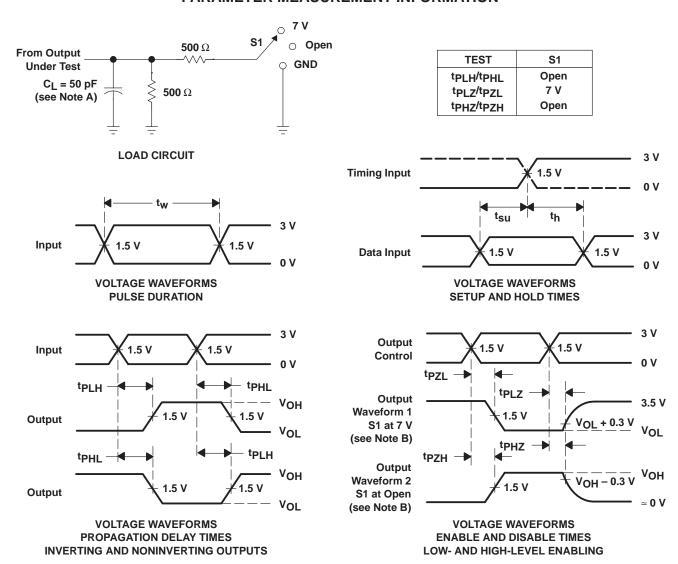
switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 5 V, T _A = 25°C			SN54ABT651		SN74ABT651		UNIT	
	(INFOT)	(001F01)	MIN	TYP	MAX	MIN	MAX	MIN	MAX		
f _{max}			125			125		125		MHz	
^t PLH	CLKBA or CLKAB	A or B	2.2	4	5.1	2.2	5.9	2.2	5.6	20	
^t PHL	CERBA OF CERAB	A or B	1.7	4	5.1	1.7	5.9	1.7	5.6	ns	
^t PLH	A or B	B or A	1.5	4	5.1	1.5	6.4	1.5	6.2	ns	
^t PHL	AOIB	B OI A	1.5	3.3	4.6	1.5	5.6	1.5	5.4	115	
t _{PLH}	CAD as CDAT	A or B	1.5	4	5.1	1.5	6.8	1.5	6.5	ns	
^t PHL	SAB or SBA†		1.5	3.6	4.9	1.5	6.2	1.5	5.9		
^t PZH	OEBA	А	1.3	3.6	4.6	1.3	5.9	1.3	5.8	ns	
t _{PZL}	OEBA		2.5	5.7	6.8	2.5	8.9	2.5	8.5	115	
^t PHZ	OEBA	А	1.5	3.2	4.5	91.5	6.2	1.5	5	ns	
^t PLZ	OEBA		1.5	3	3.8	1.5	4.3	1.5	4.1	115	
^t PZH	OEAB	В	1.8	4.3	6.1	1.8	6.7	1.8	6.5	ns	
tPZL	OLAB	ט	2.9	5.5	6.5	2.9	7.6	2.9	7.4	115	
^t PHZ	OEAB	В	1.5	3.3	4.5	1.5	6.5	1.5	5.5	ns	
^t PLZ	OLAB	ь	1.5	3.4	4.4	1.5	5.2	1.5	5.1		

[†] These parameters are measured with the internal output state of the storage register opposite that of the bus input.

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PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 2. Load Circuit and Voltage Waveforms







PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN74ABT651DBLE	OBSOLETE	SSOP	DB	24		TBD	Call TI	Call TI
SN74ABT651DBR	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ABT651DBRE4	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ABT651DW	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ABT651DWE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ABT651DWR	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ABT651DWRE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ABT651NSR	ACTIVE	SO	NS	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ABT651NSRE4	ACTIVE	SO	NS	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ABT651NT	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
SN74ABT651NTE4	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC

 $^{(1)}$ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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